

FDC6901L

Integrated Load Switch

Features

- Three Programmable Slew Rates
- Reduces Inrush Current
- Minimizes EMI
- Normal Turn-Off Speed
- Low-Power CMOS Operates Over Wide Voltage Range
- High Performance Trench Technology for Extremely low $R_{DS(ON)}$
- RoHS Compliant

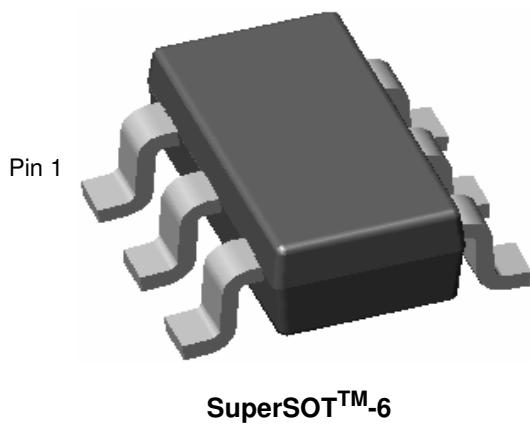
Applications

- Load switch
- Power management



General Description

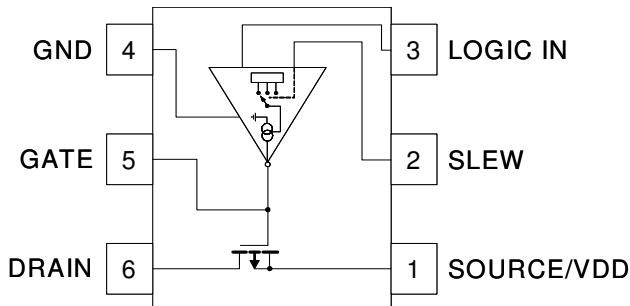
This device is particularly suited for compact power management. In portable electronic equipment where 2.5V to 6V input capability is needed. This load switch integrates a Slew Rate Control Driver that drives a P-Channel Power MOSFET in one tiny SuperSOT™-6 package. The integrated slew rate control driver is specifically designed to control the turn on of the P-Channel MOSFET in order to limit the inrush current in battery switching applications with high capacitance loads. For turn-off, the IC pulls the MOSFET gate up quickly.



Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
.901	FDC6901L	7"	8mm	3000 units

Pin Configuration



Absolute Maximum Ratings

Parameter	Min.	Max.	Unit
Supply Voltage	-0.5	10	V
DC Input Voltage (Logic Inputs)	-0.7	9	V
Power Dissipation			
Storage Junction Temperature	-55	150	°C
Thermal Resistance, Junction to Ambient		180	°C/W
Thermal Resistance, Junction to Case		60	°C/W

Recommended Operating Range

Parameter	Min.	Max.	Unit
Supply Voltage	2.7	6	V
Operating Junction Temperature	-55	150	°C

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Logic Levels						
Logic High Input Voltage	V_{IH}	$V_{DD} = 2.7\text{V}$ to 6.0V	70% V_{DD}			V
Logic Low Input Voltage	V_{IL}	$V_{DD} = 2.7\text{V}$ to 6.0V			25% V_{DD}	V
Off Characteristics - Slew Rate Control Driver						
Supply Input Breakdown Voltage	BV_{DG}	$I_{DG} = 10\mu\text{A}$, $V_{IN} = 0\text{V}$, $V_{SLEW} = 0\text{V}$	9			V
Slew Input Breakdown Voltage	BV_{SLEW}	$I_{SLEW} = 10\mu\text{A}$, $V_{IN} = 0\text{V}$	9			V
Logic Input Breakdown Voltage	BV_{IN}	$I_{IN} = 10\mu\text{A}$, $V_{SLEW} = 0\text{V}$	9			V
Supply Input Leakage Current	IR_{DG}	$V_{DG} = 8\text{V}$, $V_{IN} = 0\text{V}$, $V_{SLEW} = 0\text{V}$			100	nA
Slew Input Leakage Current	IR_{SLEW}	$V_{SLEW} = 8\text{V}$, $V_{IN} = 0\text{V}$			100	nA
Logic Input Leakage Current	IR_{IN}	$V_{IN} = 8\text{V}$, $V_{SLEW} = 0\text{V}$			100	nA
Off Characteristics - Slew Rate Control Driver + P-Channel MOSFET						
MOSFET Breakdown Voltage	BV_{DSS}	$I_D = -250\mu\text{A}$	9			V
MOSFET Leakage Current	I_{DSS}	$V_R = 16\text{V}$			100	nA
On Characteristics - Slew Rate Control Driver						
Output/Gate Current	I_G	$I_D = -250\mu\text{A}$	Slew Pin = Open	90		μA
			Slew Pin = GND	1		μA
			Slew Pin = V_{DD}	10		nA

Electrical Characteristics Cont.

$T_A = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
On Characteristics - P-Channel MOSFET						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = -250\mu\text{A}$	-0.6	-1	-1.5	V
Static Drain-Source On Resistance	$R_{DS(\text{ON})}$	$V_{GS} = -4.5\text{V}$, $I_D = -1.5\text{A}$		120	145	$\text{m}\Omega$
		$V_{GS} = -2.5\text{V}$, $I_D = -1.2\text{A}$		170	210	$\text{m}\Omega$
On Characteristics - Slew Rate Control Driver + P-Channel MOSFET						
Dropout Voltage	V_{DROP}	$V_{DD} = 6\text{V}$, $V_{IN} = 2.5\text{V}$ to 6V , $I_L = 1.5\text{A}$		160	300	mV
		$V_{DD} = 6\text{V}$, $V_{IN} = 2.5\text{V}$ to 6V , $I_L = 1.2\text{A}$		130	300	mV
Load Switch On Resistance	R_{ON}	$V_{DD} = 6\text{V}$, $V_{IN} = 2.5\text{V}$ to 6V , $I_L = 1.5\text{A}$		105	180	$\text{m}\Omega$
		$V_{DD} = 6\text{V}$, $V_{IN} = 2.5\text{V}$ to 6V , $I_L = 1.2\text{A}$		110	210	$\text{m}\Omega$
Load Current	I_{LOAD}	$V_{GS} = 2.5\text{V}$, $V_{DS} = 6\text{V}$	3			A
P-Channel Switching Times ($V_{\text{SUPPLY}} = 5.5\text{V}$, $V_{DD} = 5.5\text{V}$, Logic IN = 5.5V, $I_{\text{LOAD}} = 1.5\text{A}$)						
Delay On Time	t_{dON}	Slew Pin	= Open		6.2	μs
			= GND		42	μs
			= V_{DD}		115	μs
V_{OUT} Rise Time	t_R	Slew Pin	= Open		6.75	μs
			= GND		124	μs
			= V_{DD}		162	μs
Output Slew Rate	dv/dt	Slew Pin	= Open		600	V/ms
			= GND		41	V/ms
			= V_{DD}		24	V/ms

Typical Characteristics

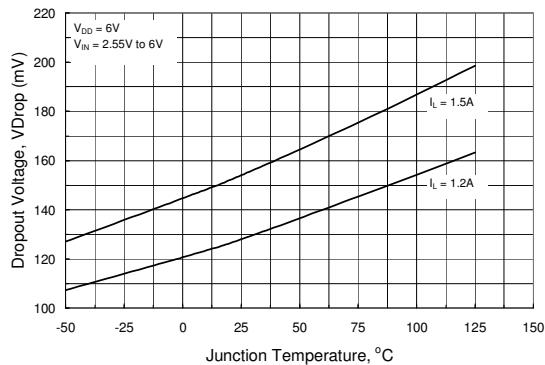


Figure 1. Dropout Voltage vs. Temperature
(SLEW = OPEN)

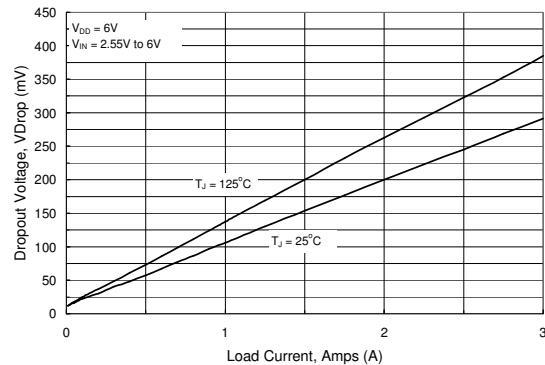


Figure 2. Dropout Voltage vs. Load Current
(SLEW = OPEN)

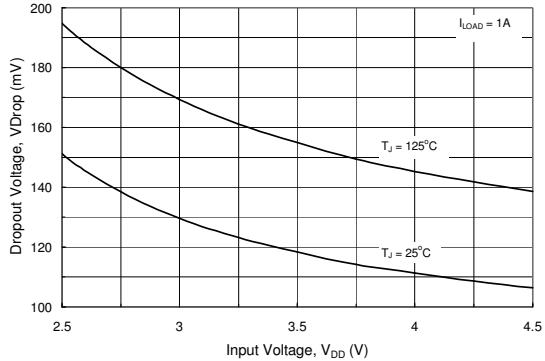


Figure 3. Dropout Voltage vs. Input Voltage
(SLEW = OPEN)

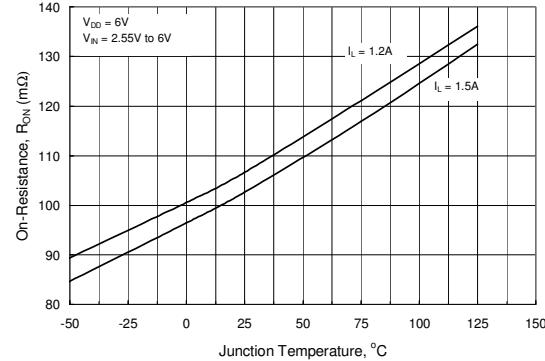


Figure 4. On Resistance vs. Temperature
(SLEW = OPEN)

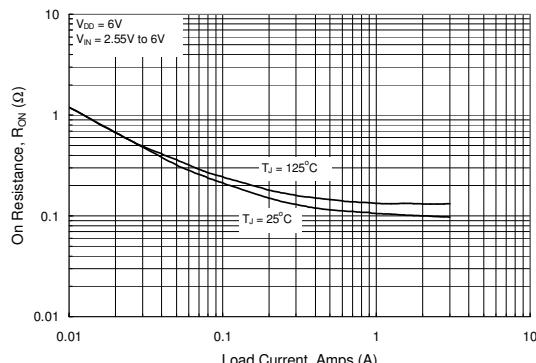


Figure 5. On Resistance vs. Load Current
(SLEW = OPEN)

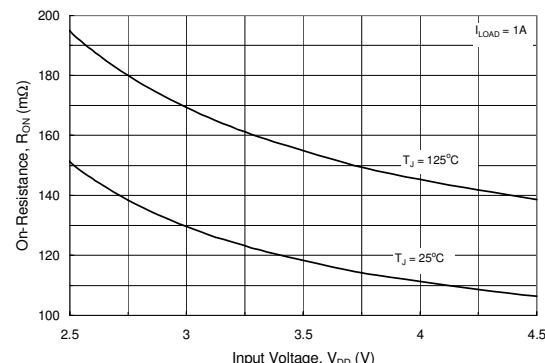


Figure 6. On Resistance vs. Input Voltage
(SLEW = OPEN)

Typical Characteristics

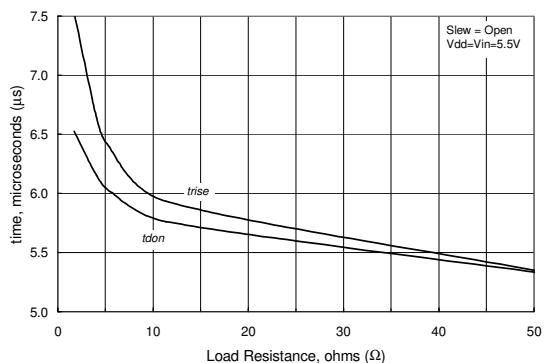


Figure 7. Switching Time vs. Load Resistance
(SLEW = OPEN)

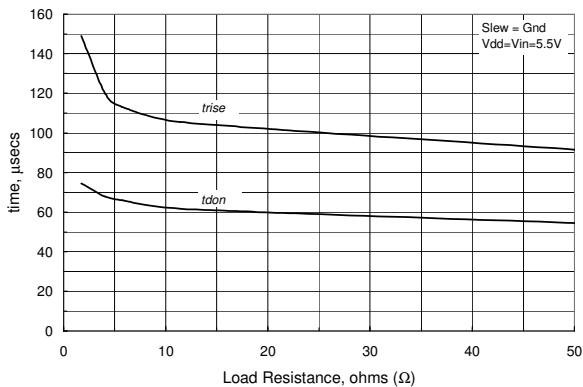


Figure 8. Switching Time vs. Load Resistance
(SLEW = GROUND)

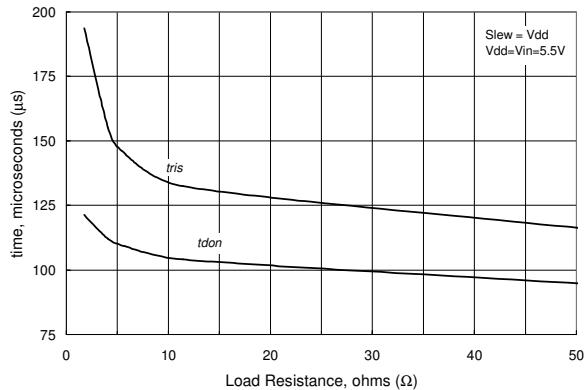


Figure 9. Switching Time vs. Load Resistance
(SLEW = V_{DD})

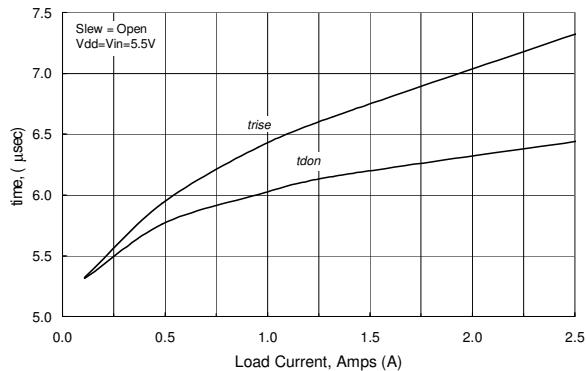


Figure 10. Switching Time vs. Load Current
(SLEW = OPEN)

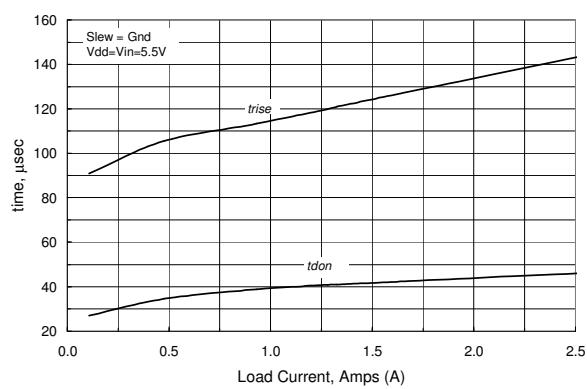


Figure 11. Switching Time vs. Load Current
(SLEW = GROUND)

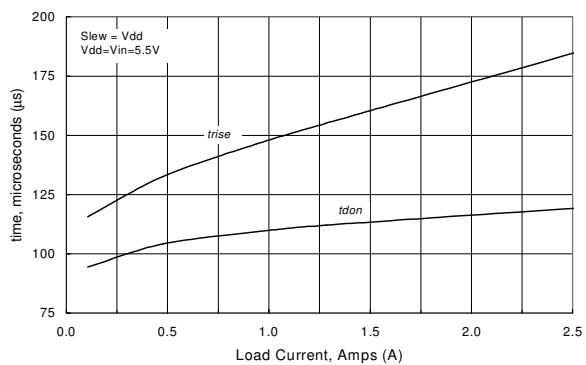
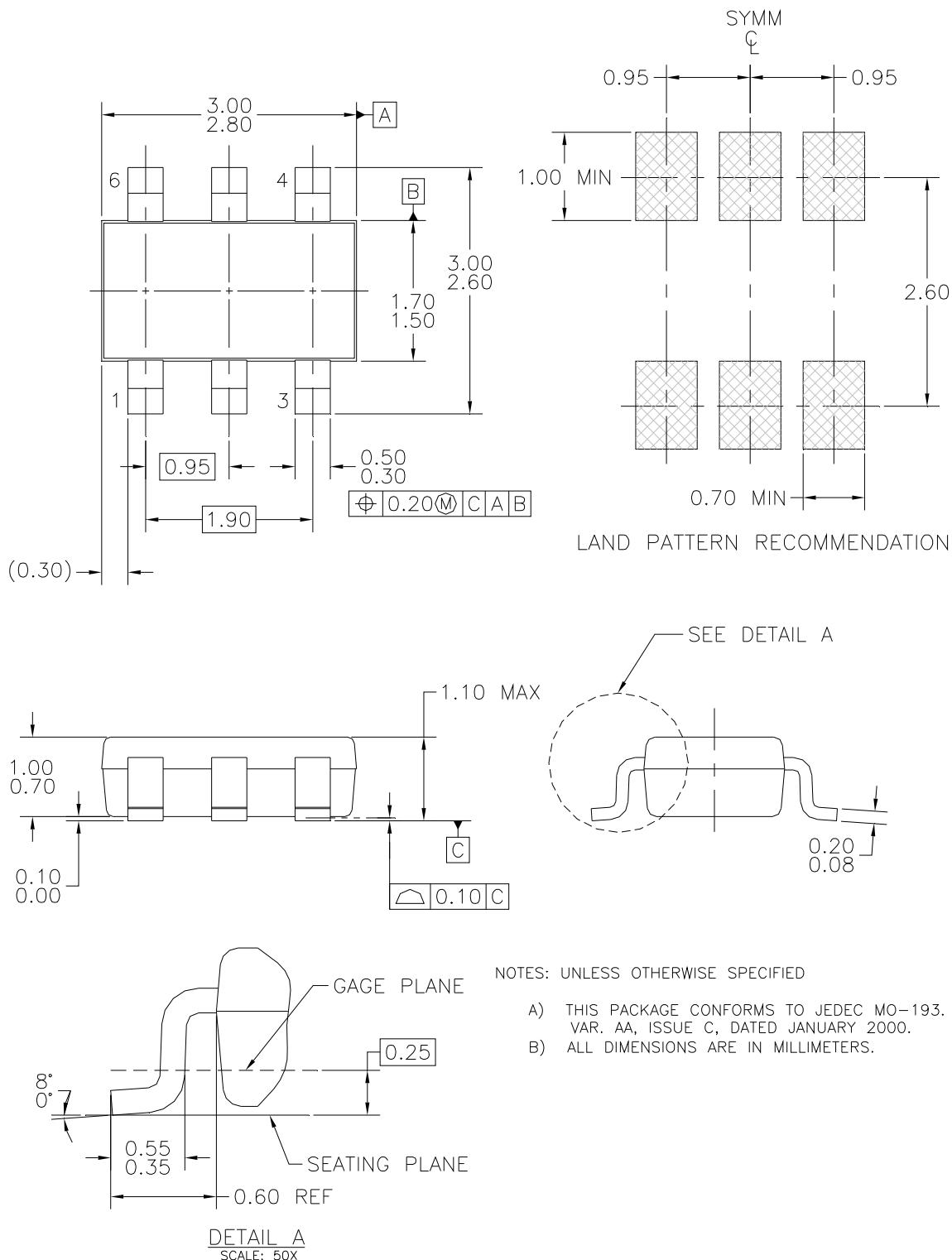


Figure 12. Switching Time vs. Load Current
(SLEW = V_{DD})

Dimensional Outline and Pad Layout





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